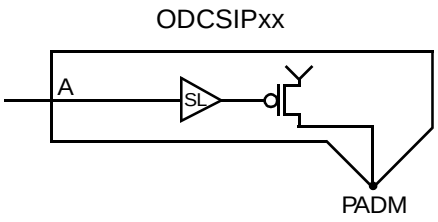
Description

ODCSIPxx is a family of 4 to 8 mA, inverting, CMOS-level output buffer pieces with P-channel open-drains (pull-up) and controlled slew rate outputs.

Logic Symbol



Truth Table

A	PADM
L	H
H	Z

Z = High Impedance

HDL Syntax

Verilog ..... ODCSIPxx *inst_name* (PADM, A);

VHDL..... *inst_name*: ODCSIPxx port map (PADM, A);

Pin Loading

Pin Name	Load		
	ODCSIP04	ODCSIP08	ODCSIP12
A (eq-load)	4.1	4.1	4.1
PADM (pF)	4.94	4.94	4.94

Power Characteristics

Cell	Output Drive (mA)	Power Characteristics[a]	
		Static I_{DD} (T_J = 85°C) (nA)	EQL_{pd} (Eq-load)
ODCSIP04	4	TBD	190.5
ODCSIP08	8	TBD	203.6
ODCSIP12	12	TBD	216.8

a. See page 2-15 for power equation.

AMI5HG 0.5 micron CMOS Gate Array

Propagation Delays (ns)

Conditions: T_J = 25°C, V_{DD} = 5.0V, Typical Process

ODCSIP04	**Capacitive Load (pF)**		**15**	**50**	**100**	**200**	**300 (max)**
	From: A To: PADM	t_{ZH}	2.64	6.29	11.51	21.93	32.36
ODCSIP08	**Capacitive Load (pF)**		**15**	**50**	**100**	**200**	**300 (max)**
	From: A To: PADM	t_{ZH}	1.75	3.62	6.31	11.65	16.94
ODCSIP12	**Capacitive Load (pF)**		**15**	**50**	**100**	**200**	**300 (max)**
	From: A To: PADM	t_{ZH}	1.60	2.88	4.68	8.26	11.86

Delay will vary with input conditions. See page 2-17 for interconnect estimates.

Tristate Timing

Conditions: T_J = 25°C, V_{DD} = 5.0V, Typical Process

Delay (ns)		Parameter	Cell		
From	**To**		**ODCSIP04**	**ODCSIP08**	**ODCSIP12**
A	PADM	t_{HZ}	0.78	1.01	1.23